





#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.015 grams (Approximate)

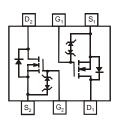






SOT26

Top View



Top View Internal Schematic

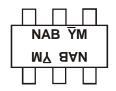
### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2004DMK-7	SOT26	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



 $\begin{aligned} & \text{NAB = Marking Code} \\ & \text{YM = Date Code Marking} \\ & \overline{Y} = \text{Year (ex: T = 2006)} \\ & \text{M = Month (ex: 9 = September)} \end{aligned}$ 

Date Code Kev

2410 0040 11												
Year	2006	~	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	T	~	D	Е	F	G	H		J	K	L	M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	Characteristic	Symbol	Value	Units	
Drain-Source Voltage			V <sub>DSS</sub>	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±8	V
Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +85°C	I <sub>D</sub>	540 390	mA
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	1.5	Α

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	$P_{D}$	225	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-65 to +150	°C

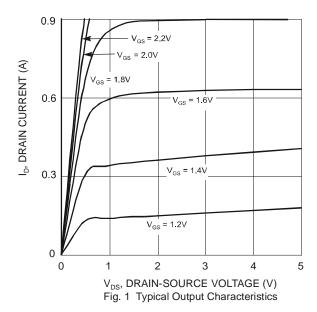
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			. , , ,	mux	, <b>O</b>	1001 Containen
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_		1	μΑ	V <sub>DS</sub> = 16V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±1	μΑ	$V_{GS} = \pm 4.5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	0.5		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	0.4 0.5 0.7	0.55 0.70 0.9	Ω	$V_{GS} = 4.5V, I_D = 540mA$ $V_{GS} = 2.5V, I_D = 500mA$ $V_{GS} = 1.8V, I_D = 350mA$
Forward Transfer Admittance	Y <sub>FS</sub>	200		_	ms	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>ISS</sub>	_	_	150	pF	101/1/
Output Capacitance	Coss	_		25	pF	$V_{DS} = 16V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>RSS</sub>	_		20	pF	T = T.OIVII IZ

Notes:

- Device mounted on FR-4 PCB.
   Pulse width ≤10µS, Duty Cycle ≤1%.
   Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to product testing.





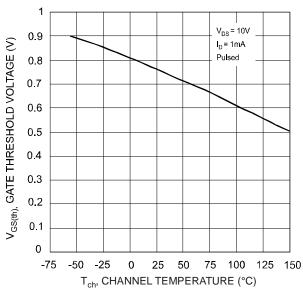


Fig. 3 Gate Threshold Voltage vs. Channel Temperature

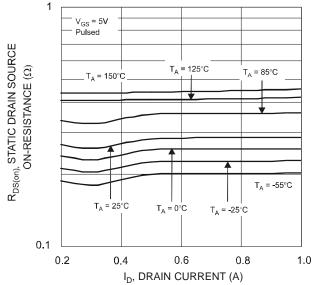


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

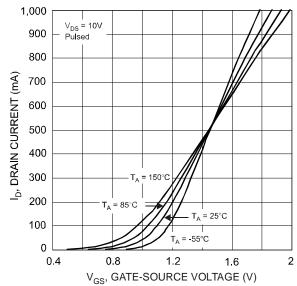


Fig. 2 Reverse Drain Current vs. Source-Drain Voltage

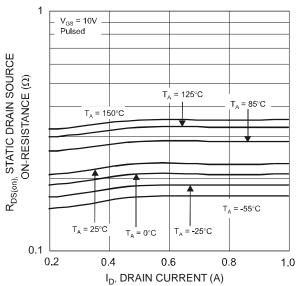
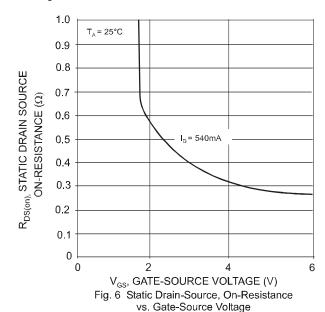


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current





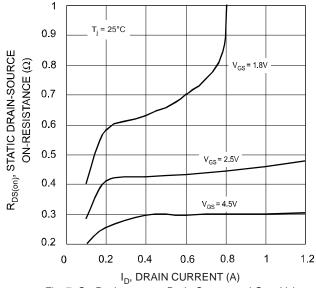
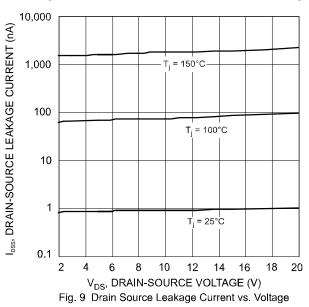


Fig. 7 On-Resistance vs. Drain Current and Gate Voltage



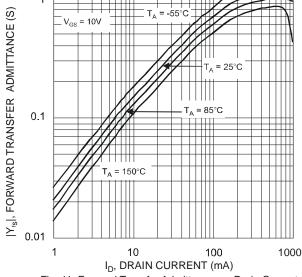


Fig. 11 Forward Transfer Admittance vs. Drain Current

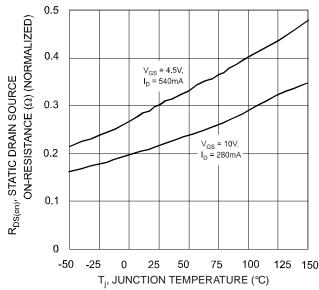


Fig. 8 Static Drain-Source, On-Resistance vs. Temperature

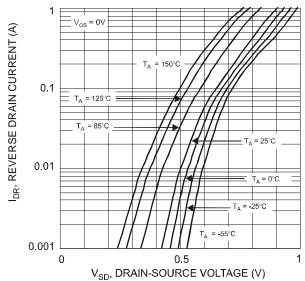
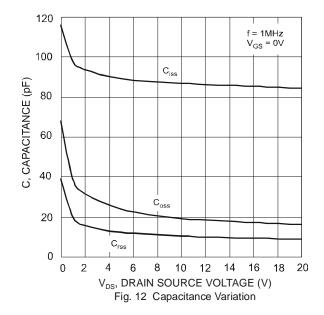


Fig. 10 Reverse Drain Current vs. Source-Drain Voltage

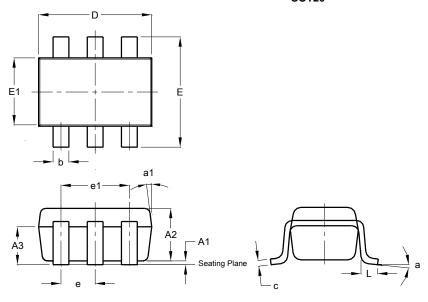




# **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOT26

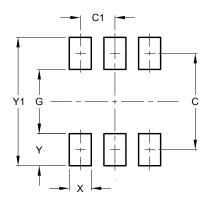


SOT26						
Dim	Min	Max	Тур			
<b>A</b> 1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
А3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	-	0.95			
e1	-	_	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	_	8°			
a1	_	-	7°			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOT26



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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